

IRS2001MPBF HIGH AND LOW SIDE DRIVER

Features

- Floating channel designed for bootstrap operation
- Fully operational to +200V
- Tolerant to negative transient voltage, dV/dt immune
- Gate drive supply range from 10V to 20V
- Undervoltage lockout
- 3.3V, 5V, and 15V logic compatible
- Cross-conduction prevention logic
- Matched propagation delay for both channels
- Outputs in phase with inputs
- Leadfree, RoHS compliant

Description

The IRS2001 is a high voltage, high speed power MOSFET and IGBT driver with dependent high and low side referenced output channels. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. The logic input is compatible with standard CMOS or LSTTL output, down to 3.3V logic. The output drivers feature a high pulse current buffer stage designed for minimum driver crossconduction. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high side configuration which operates up to 200V.

Product Summary

Topology	General Driver
V _{OFFSET}	≤ 200V
V _{OUT}	10V – 20V
I _{o+} & I _{o-} (typical)	290mA & 600mA
t _{on} & t _{off} (typical)	160ns & 150ns
Delay Matching (Max.)	50ns

Package Options



MLPQ4x4 - 16 Leads (Without 2 leads)

Typical Connection Vcc VBHIN LIN VSCOM LOAD (Refer to Lead Assignments for correct pin configuration) This diagram shows electrical connections only. Please refer to our Application Notes and Design Tips for proper circuit board layout.

Qualification Information[†]

Qualification into	ormation					
			Industrial ^{††} (per JEDEC JESD 47)			
Qualification Level		Comments: This IC has passed JEDEC's Industrial qualification. IR's Consumer qualification level is granted by extension of the higher Industrial level.				
Moisture Sensitivity I	_evel	MLPQ4x4 14L	MSL2 ^{†††} (per IPC/JEDEC J-STD-020)			
	Machine Model	Class A (+/-200V)				
	Machine Model	(per JEDEC standard JESD22-A115A)				
ESD	Human Body Model	Class 1C (+/-2000V)				
200	Traman Body Woder	(per JEDEC standard JESD22-A114F)				
	Charged Device Model	Class III (+/-1000V)				
	Charged Device Woder	(per JEDEC standard JESD22-C101D)				
IC Latch-Up Test		Class II, Level B				
		(per AEC-Q100-004)				
RoHS Compliant			Yes			

- † Qualification standards can be found at International Rectifier's web site http://www.irf.com/
- †† Higher qualification ratings may be available should the user have such requirements. Please contact your International Rectifier sales representative for further information.
- ††† Higher MSL ratings may be available for the specific package types listed here. Please contact your International Rectifier sales representative for further information.



Absolute Maximum Ratings

Absolute Maximum Ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

Symbol	Definition	Min.	Max.	Units
V_B	High side floating absolute voltage	-0.3	225	
Vs	High side floating supply offset voltage	V _B - 25	V _B + 0.3	
V_{HO}	High side floating output voltage	V _S - 0.3	V _B + 0.3	V
V_{CC}	Low side and logic fixed supply voltage	-0.3	25	v
V_{LO}	Low side output voltage	-0.3	$V_{CC} + 0.3$	
V _{IN}	Logic input voltage (HIN & LIN)	-0.3	$V_{CC} + 0.3$	
dV _S /dt	Allowable offset supply voltage transient	_	50	V/ns
P_{D}	Package power dissipation @ TA ≤ 25°C	_	2.08	W
Rth_JA	Thermal resistance, junction to ambient	_	36	°C/W
T_J	Junction temperature	_	150	
Ts	Storage temperature	-55	150	°C
TL	Lead temperature (soldering, 10 seconds)	_	300	

Recommended Operating Conditions

The input/output logic timing diagram is shown in Fig 1. For proper operation the device should be used within the recommended conditions. The $V_{\rm S}$ offset rating is tested with all supplies biased at 15V differential.

Symbol	Definition	Min.	Max.	Units
V_B	High side floating supply absolute voltage	V _S + 10	V _S + 20	
Vs	High side floating supply offset voltage	†	200	
V_{HO}	High side floating output voltage	Vs	V_{B}	W
V_{CC}	Low side and logic fixed supply voltage	10	20	v
V_{LO}	Low side output voltage	0	V_{CC}	
V_{IN}	Logic input voltage	0	V_{CC}	
T _A	Ambient temperature	-40	125	°C

[†] Logic operational for V_S of -5V to +200V. Logic state held for V_S of -5V to $-V_{BS}$. (Please refer to the Design Tip DT97-3 for more details).

Dynamic Electrical Characteristics

 V_{BIAS} (V_{CC} , V_{BS}) = 15V, C_L = 1000pF, T_A = 25°C unless otherwise specified.

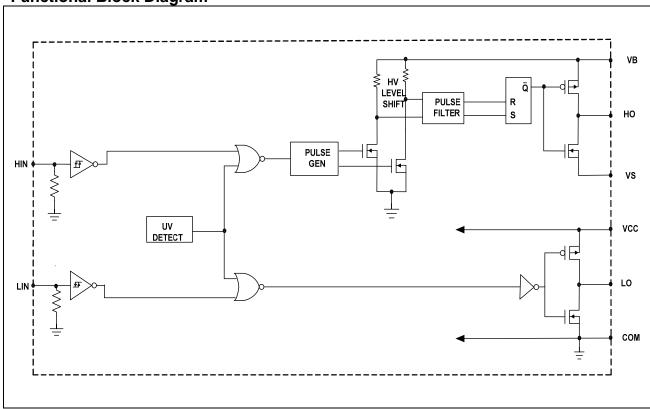
Symbol	Definition	Min	Тур	Max	Units	Test Conditions
t _{on}	Turn-on propagation delay	_	160	220		$V_S = 0V$
t_{off}	Turn-off propagation delay	_	150	220		V _S = 200V
t _r	Turn-on rise time	_	70	170	ns	
t _f	Turn-off fall time	_	35	90		
MT	Delay Matching, HS & LS turn-on/off	_	_	50		

Static Electrical Characteristics

 $V_{\text{BIAS}}(V_{\text{CC}}, V_{\text{BS}})$ = 15V and I_{A} = 25°C unless otherwise specified. The V_{IN} , V_{TH} , and I_{IN} parameters are referenced to COM. The V_{O} and I_{O} parameters are referenced to COM and are applicable to the respective output leads: HO and LO.

Symbol	Definition	Min	Тур	Max	Units	Test Conditions
V_{IH}	Logic "1" input voltage	2.5	_			V _{CC} = 10V to 20V
V_{IL}	Logic "0" input voltage		_	0.8	V	V _{CC} = 10V to 20V
V_{OH}	High level output voltage, V_{BIAS} - V_{O}		0.05	0.2	ď	I _O = 2mA
V_{OL}	Low level output voltage, Vo		0.02	0.1		1 ₀ = 2111A
I _{LK}	Offset supply leakage current		_	50		$V_{B} = V_{S} = 200V$
I_{QBS}	Quiescent V _{BS} supply current	_	30	55		\/ = 0\/ or 5\/
I _{QCC}	Quiescent V _{CC} supply current	_	150	270	μA	$V_{IN} = 0V \text{ or } 5V$
I _{IN+}	Logic "1" input bias current	_	3	10		V _{IN} = 5V
I _{IN-}	Logic "0" input bias current	_	_	5		$V_{IN} = 0V$
V _{CCUV+}	V _{CC} supply undervoltage positive going threshold	8.0	8.9	9.8	V	
V _{CCUV-}	V _{CC} supply undervoltage negative going threshold	7.4	8.2	9.0	V	
I _{O+}	Output high short circuit pulsed current	130	290	_	mA	$V_O = 0V$, $V_{IN} = \text{Logic "1"}$ $PW \le 10 \mu\text{s}$
I _{O-}	Output low short circuit pulsed current	270	600	_	IIIA	$V_O = 15V$, $V_{IN} = \text{Logic "0"}$ $PW \le 10 \mu \text{s}$

Functional Block Diagram

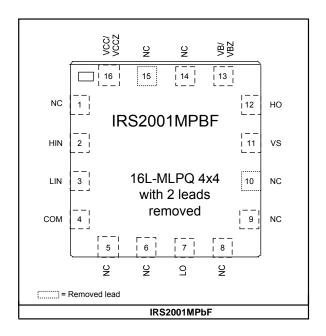




Lead Definitions

PIN	Symbol	Description
1	NC	No connection
2	HIN	Logic input for high side gate driver output (HO), in phase
3	LIN	Logic input for low side driver output (LO), in phase
4	COM	Low side return
5	NC	No Connection
6	NC	No Connection
7	LO	Low side gate drive output
8	NC	No Connection
9	NC	No Connection
10	NC	No Connection (pin removed)
11	V_S	High side floating supply return
12	НО	High side gate drive output
13	V_B/V_{BZ}	High side floating supply
14	NC	No Connection
15	NC	No Connection (pin removed)
16	V _{CC} /V _{CCZ}	Low side and logic fixed supply

Lead Assignments





Application Information and Additional Details

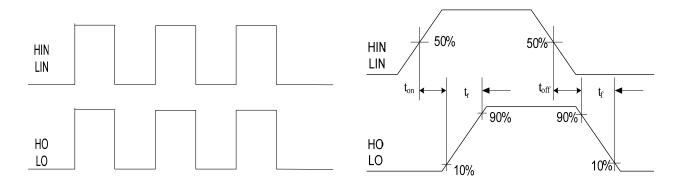


Figure 1: Input/Output Timing Diagram

Figure 2: Switching Time Waveform Definitions

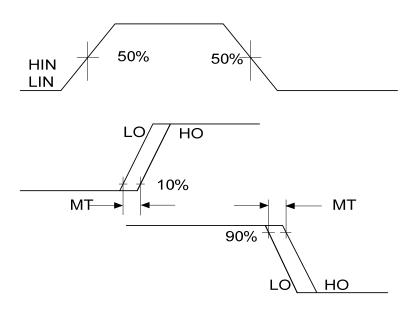


Figure 3: Delay Matching Waveform Definitions

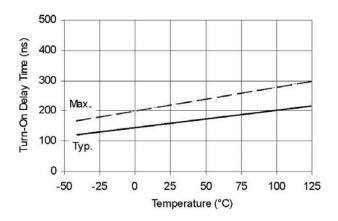


Figure 6A. Turn-On Time vs. Temperature

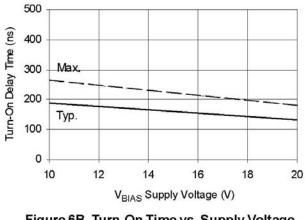


Figure 6B. Turn-On Time vs. Supply Voltage

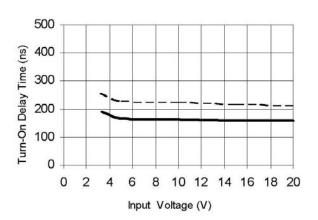


Figure 6C. Turn-On Time vs. Input Voltage

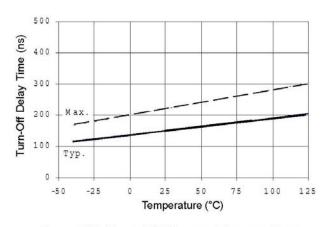


Figure 7A. Turn-Off Time vs. Temperature

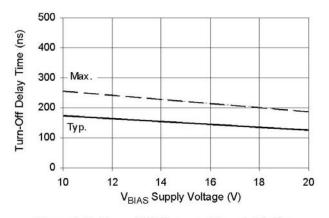


Figure 7B. Turn-Off Time vs. Supply Voltage

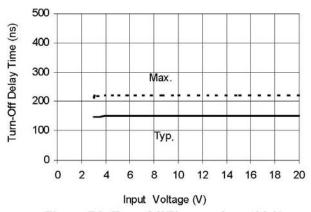


Figure 7C. Turn-Off Time vs. Input Voltage

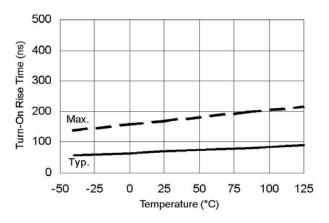


Figure 9A. Turn-On Rise Time vs. Temperature

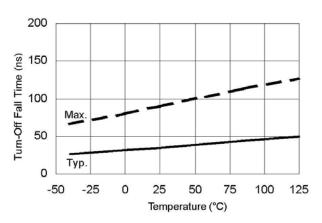


Figure 10A. Turn-Off Fall Time vs. Temperature

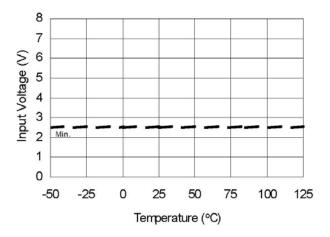


Figure 12A. Logic "1" Input Voltage vs. Temperature

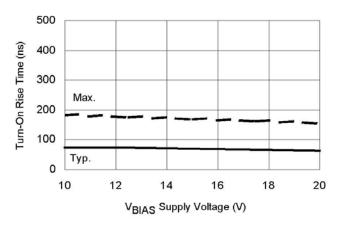


Figure 9B. Turn-On Rise Time vs. Voltage

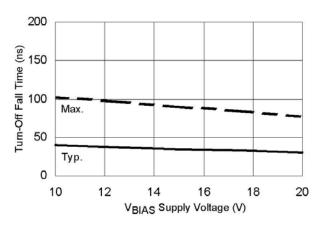


Figure 10B. Turn-Off Fall Time vs. Voltage

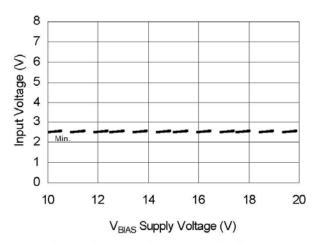


Figure 12B. Logic "1" Input Voltage vs. Voltage

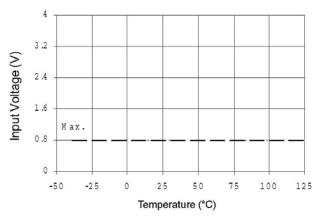
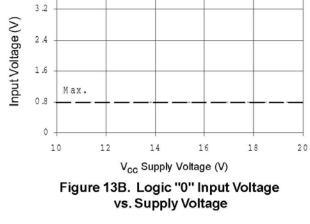


Figure 13A. Logic "0" Input Voltage vs. Temperature



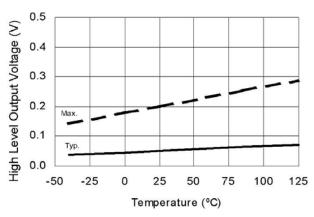


Figure 14A. High Level Output Voltage vs. Temperature

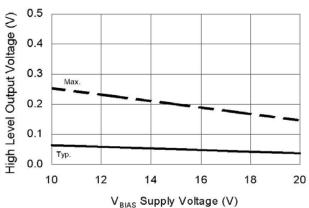


Figure 14B. High Level Output vs. Supply Voltage

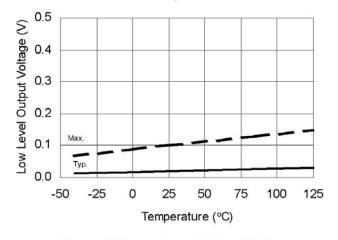


Figure 15A. Low Level Output Voltage vs. Temperature

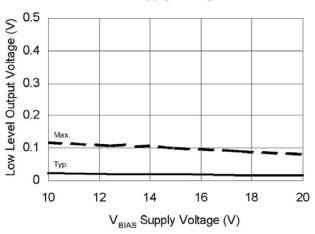


Figure 15B. Low level Output vs.Supply Voltage

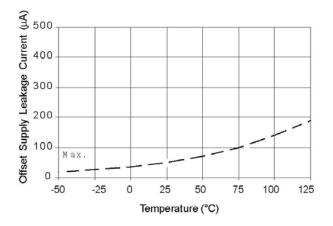


Figure 16A. Offset Supply Current vs. Temperature

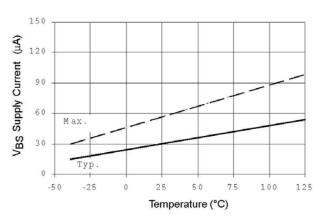


Figure 17A. V_{BS} Supply Current vs. Temperature

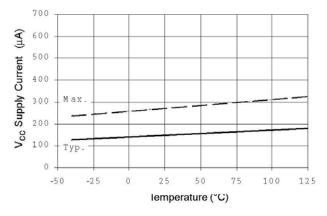


Figure 18A. V_{CC} Supply Current vs. Temperature

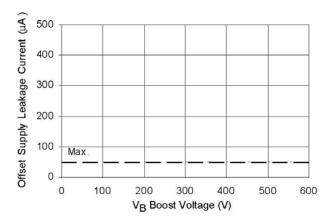


Figure 16B. Offset Supply Current vs. Voltage

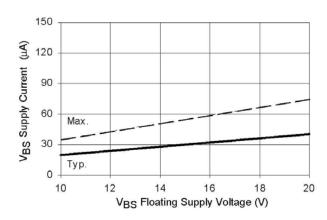


Figure 17B. V_{BS} Supply Current vs. Voltage

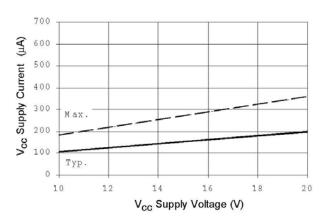


Figure 18B. V_{CC} Supply Current vs. Voltage

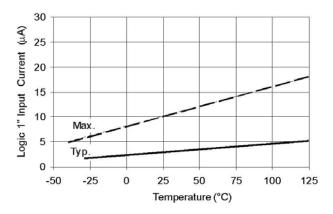


Figure 19A. Logic"1" Input Current vs. Temperature

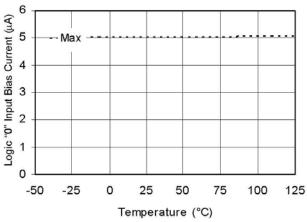


Figure 20A. Logic "0" Input Bias Current vs. Temperature

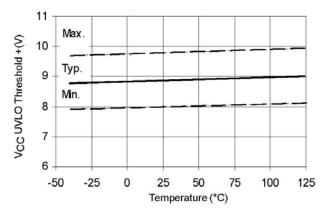


Figure 21A. V_{CC} Undervoltage Threshold(+) vs. Temperature

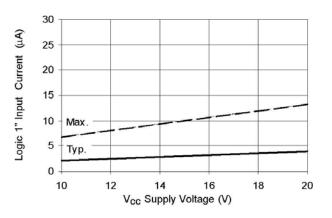


Figure 19B. Logic"1" Input Current vs. Voltage

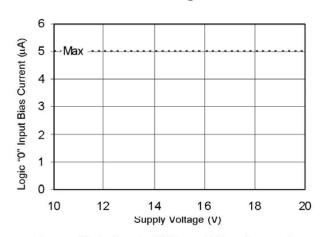


Figure 20B. Logic "0" Input Bias Current vs. Voltage

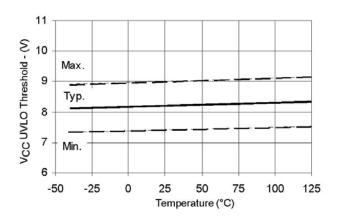


Figure 21B. V_{CC} Undervoltage Threshold(-) vs. Temperature

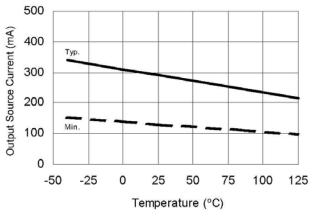


Figure 22A. Output Source Current vs. Temperature

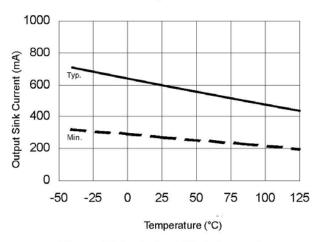


Figure 23A. Output Sink Current vs. Temperature

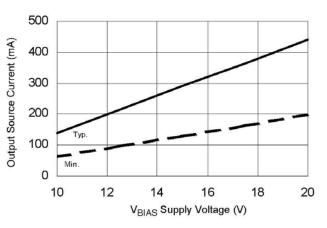


Figure 22B. Output Source Current vs. Supply Voltage

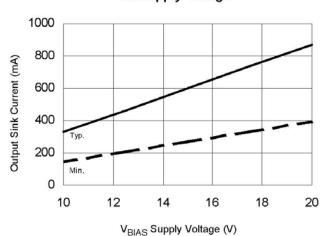
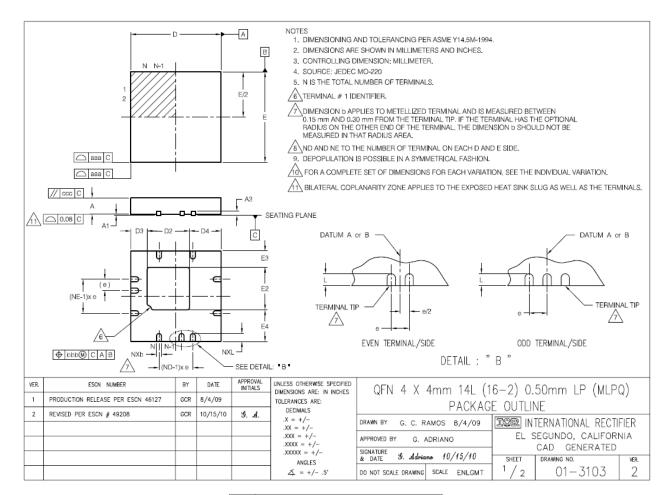


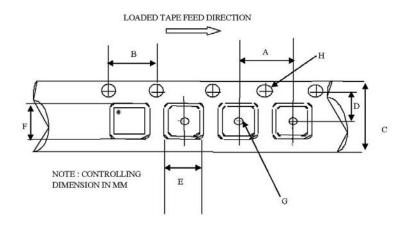
Figure 23B. Output Sink Current vs. Supply Voltage

Package Details: MLPQ 4x4 -14L



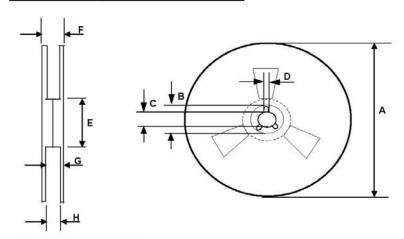
SYM		VGGD-10				
M B O L	MILLIMETERS				INCHES	
Ľ	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.80	0.90	1.00	.032	.035	.039
A1	0.00	0.02	0.05	.000	.0008	.0019
A3		0.20 REF	=		.008 REF	
b	0.18	0.25	0.30	.007	.010	.012
D2	1.78	1.88	1.98	.070	.074	.078
D3		0.73 REF	=		.029 REF	
D4		1.40 REF			.055 REF	
D		4.00 BS0)	.157 BSC		
Е		4.00 BS0	0	.157 BSC		
E4		0.73 REF	=	.029 REF		
E3		1.40 REF	=		.055 REF	
E2	1.78	1.88	1.98	.070	.074	.078
L	0.30	0.40	0.50	.012	.016	.020
е		0.50 PITC	H	.(020 PITCI	Н
N		16			16	
ND	4				4	
NE	4				4	
aaa	0.15				.0059	
bbb	0.10				.0039	
CCC		0.10			.0039	
ddd		0.05			.0019	

Tape and Reel Details: MLPQ 4x4 - 14L



CARRIER TAPE DIMENSION FOR MLPQ4X4V

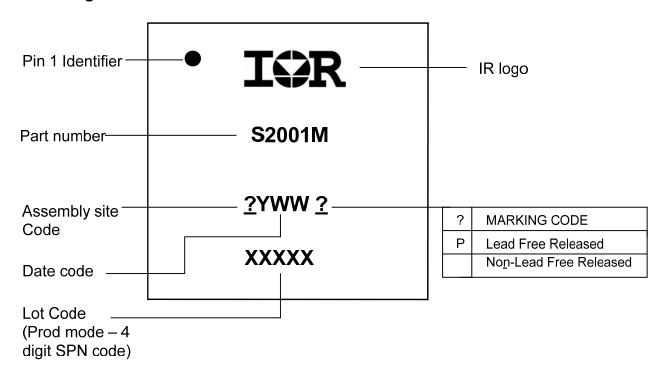
	Me	tric	lmp	erial
Code	Min	Max	Min	Max
A	7.90	8.10	0.311	0.358
В	3.90	4.10	0.154	0.161
C D	11.70	12.30	0.461	0.484
D	5.45	5.55	0.215	0.219
E	4.25	4.45	0.168	0.176
F	4.25	4.45	0.168	0.176
G	1.50	n/a	0.059	n/a
G H	1.50	1.60	0.059	0.063



REEL DIMENSIONS FOR MLPQ4X4V

	Me	tric	Imp	erial
Code	Min	Max	Min	Max
A	329.60	330.25	12.976	13.001
В	20.95	21.45	0.824	0.844
A B C D E F G	12.80	13.20	0.503	0.519
D	1.95	2.45	0.767	0.096
E	98.00	102.00	3.858	4.015
F	n/a	18.40	n/a	0.724
G	14.50	17.10	0.570	0.673
Н	12.40	14.40	0.488	0.566

Part Marking Information



Ordering Information

Dana Bart Namel an	Standard Pack			
Base Part Number	Package Type	Form		Complete Part Number
ID00004	MLPQ 4x4-14L	Tube/Bulk	92	IRS2001MPBF
IRS2001	WILFQ 4X4-14L	Tape and Reel	3,000	IRS2001MTRPBF

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Revision History

Date	Comment
9/15/09	Initial draft converted from SO8 data sheet
06/18/2010	Included Qual Info Page
11/19/2010	Updated POD